

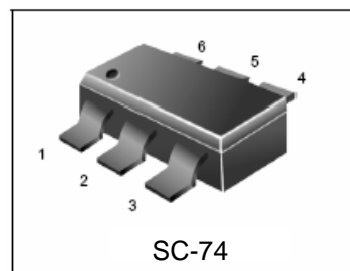
VHF/UHF Transistors

- Pb-Free Package is Available.

Ordering Information

Device	Marking	Shipping
LSBTH10T1G	H8A	3000/Tape&Reel
LSBTH10T3G	H8A	10000/Tape&Reel

LSBTH10T1G

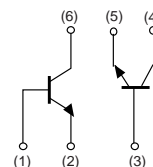


MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	V_{CEO}	25	Vdc
Collector–Base Voltage	V_{CBO}	30	Vdc
Emitter–Base Voltage	V_{EBO}	3.0	Vdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR– 5 Board, (1) $T_A = 25^\circ\text{C}$	P_D	225	mW
Derate above 25°C		1.8	mW/ $^\circ\text{C}$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	556	$^\circ\text{C}/\text{W}$
Total Device Dissipation Alumina Substrate, (2) $T_A = 25^\circ\text{C}$	P_D	300	mW
Derate above 25°C		2.4	mW/ $^\circ\text{C}$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	417	$^\circ\text{C}/\text{W}$
Junction and Storage Temperature	T_J, T_{stg}	-55 to +150	$^\circ\text{C}$



DEVICE MARKING

LSBTH10T1G = M6

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted.)

Characteristic	Symbol	Min	Typ	Max	Unit
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OFF CHARACTERISTICS

Collector–Emitter Breakdown Voltage ($I_C = 1.0 \text{ mAdc}, I_E = 0$)	$V_{(BR)CEO}$	25	—	—	Vdc
Collector–Base Breakdown Voltage ($I_C = 100 \mu\text{Adc}, I_E = 0$)	$V_{(BR)CBO}$	30	—	—	Vdc
Emitter–Base Breakdown Voltage ($I_E = 10 \mu\text{Adc}, I_C = 0$)	$V_{(BR)EBO}$	3.0	—	—	Vdc
Collector Cutoff Current ($V_{CB} = 25\text{Vdc}, I_E = 0$)	I_{CBO}	—	—	100	nAdc
Emitter Cutoff Current ($V_{EB} = 2.0\text{Vdc}, I_C = 0$)	I_{EBO}	—	—	100	nAdc

1. FR–5 = $1.0 \times 0.75 \times 0.062$ in.

2. Alumina = $0.4 \times 0.3 \times 0.024$ in. 99.5% alumina.

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ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted) (Continued)

Characteristic	Symbol	Min	Typ	Max	Unit
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ON CHARACTERISTICS

DC Current Gain ($I_C = 4.0 \text{ mA}$, $V_{CE} = 10 \text{ Vdc}$)	h_{FE}	60	—	—	—
Collector–Emitter Saturation Voltage ($I_C = 4.0 \text{ mA}$, $I_B = 0.4 \text{ mA}$)	$V_{CE(sat)}$	—	—	0.5	Vdc
Base–Emitter On Voltage ($I_C = 4.0 \text{ mA}$, $V_{CE} = 10 \text{ Vdc}$)	V_{BE}	—	—	0.95	Vdc

SMALL–SIGNAL CHARACTERISTICS

Current Gain–Bandwidth Product ($V_{CE} = 10 \text{ Vdc}$, $I_C = 4.0 \text{ mA}$, $f = 100 \text{ MHz}$)	f_T	650	—	—	MHz
Collector –Base Capacitance ($V_{CB} = 10 \text{ Vdc}$, $I_E = 0$, $f = 1.0 \text{ MHz}$)	C_{cb}	—	—	0.7	pF
Collector –Base Feedback Capacitance ($V_{CB} = 10 \text{ Vdc}$, $I_E = 0$, $f = 1.0 \text{ MHz}$)	C_{fb}	—	—	0.65	pF
Collector Base Time Constant ($I_C = 4.0 \text{ mA}$, $V_{CB} = 10 \text{ Vdc}$, $f = 31.8 \text{ MHz}$)	$r_b' C_C$	—	—	9.0	ps

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TYPICAL CHARACTERISTICS

COMMON-BASE y PARAMETERS versus FREQUENCY

($V_{CB} = 10 \text{ Vdc}$, $I_C = 4.0 \text{ mAdc}$, $T_A = 25^\circ\text{C}$)

y_{ib} , INPUT ADMITTANCE

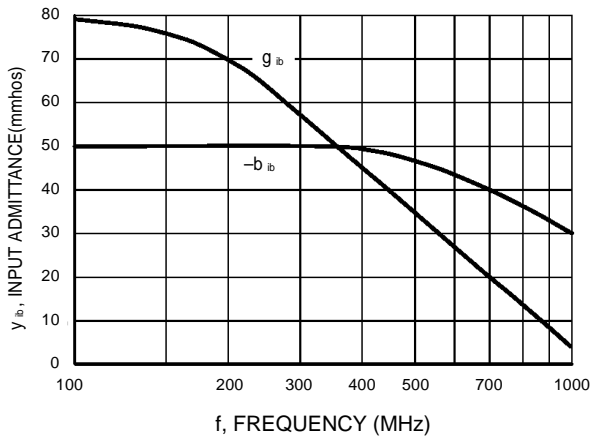


Figure 1. Rectangular Form

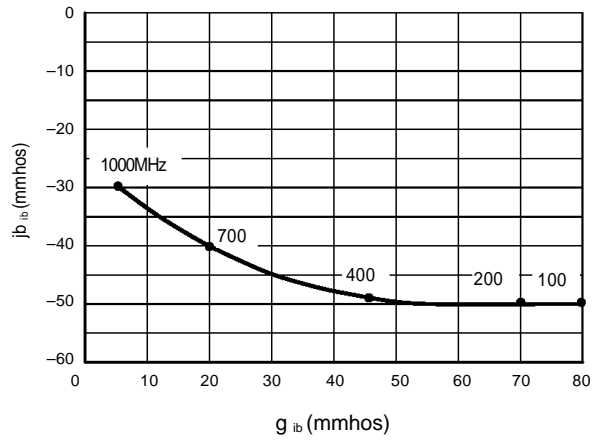


Figure 2. Polar Form

y_{fb} , FORWARD TRANSFER ADMITTANCE

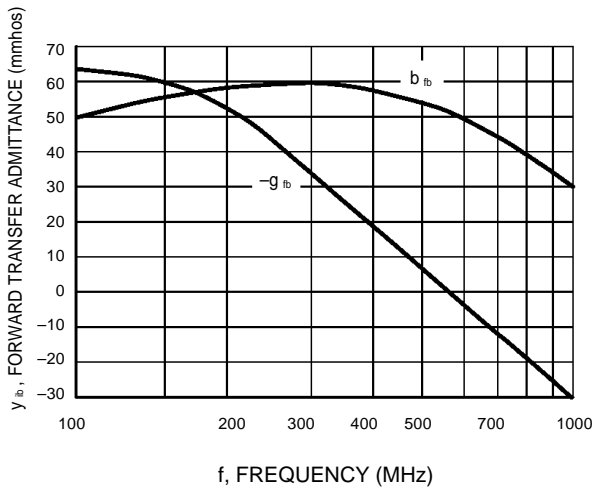


Figure 3. Rectangular Form

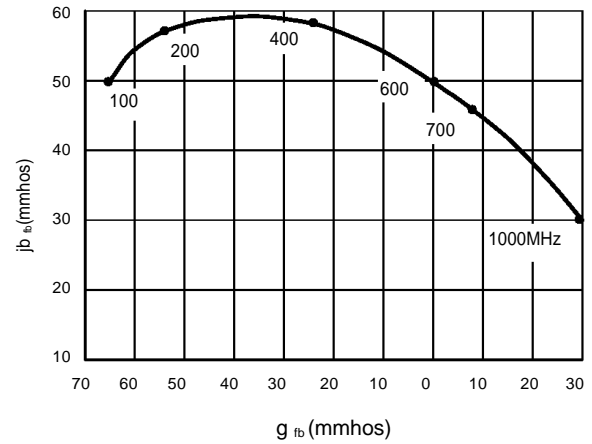


Figure 4. Polar Form

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TYPICAL CHARACTERISTICS

COMMON-BASE y PARAMETERS versus FREQUENCY

($V_{CB} = 10$ Vdc, $I_C = 4.0$ mAdc, $T_A = 25^\circ\text{C}$)

y_{rb} , REVERSE TRANSFER ADMITTANCE

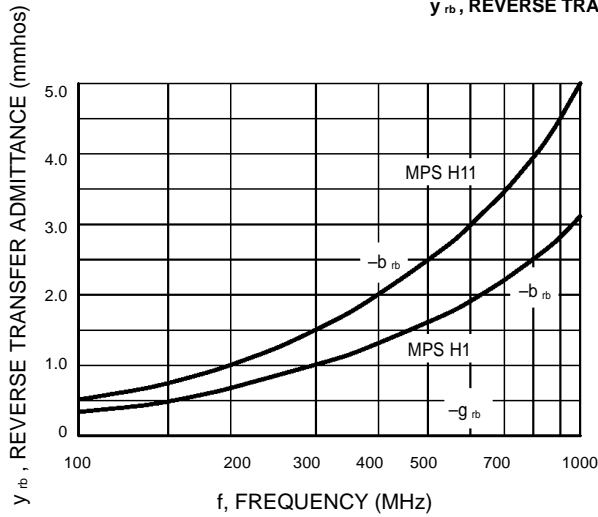


Figure 5. Rectangular Form

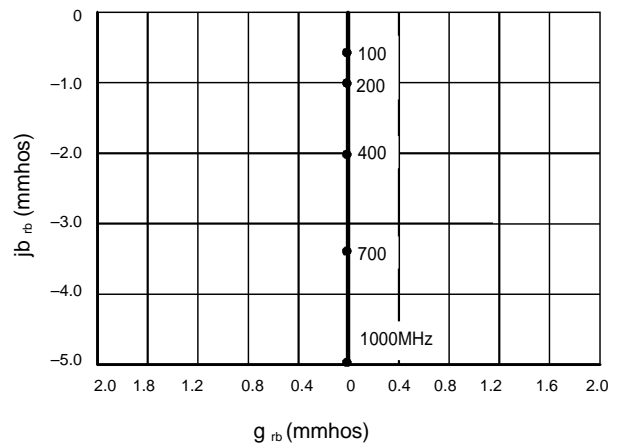


Figure 6. Polar Form

y_{ob} , OUTPUT ADMITTANCE

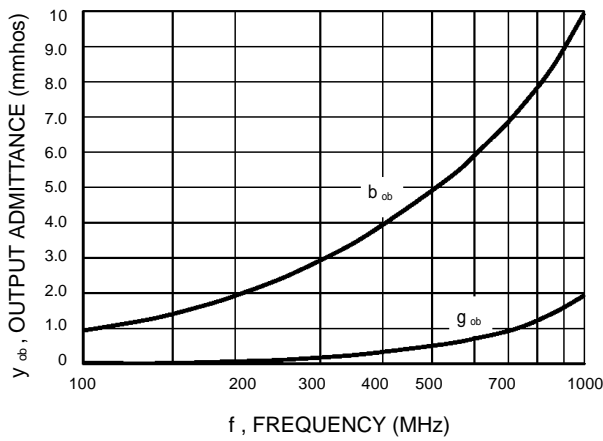


Figure 7. Rectangular Form

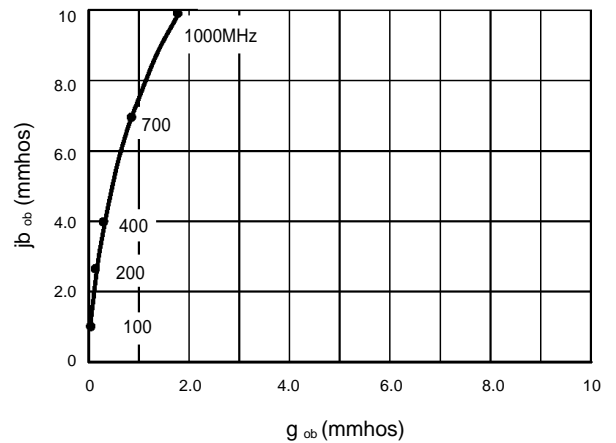
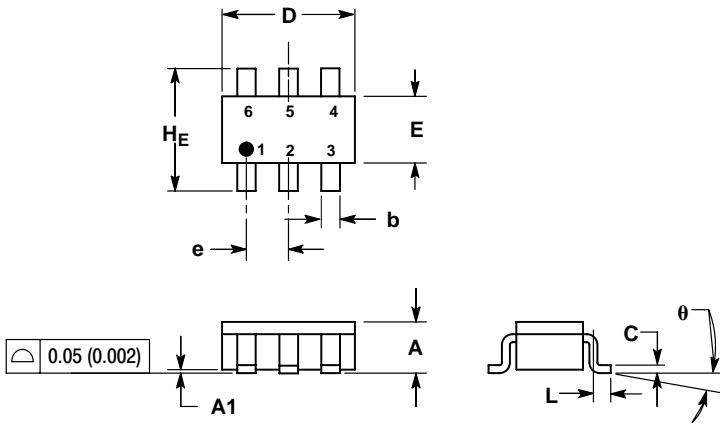


Figure 8. Polar Form

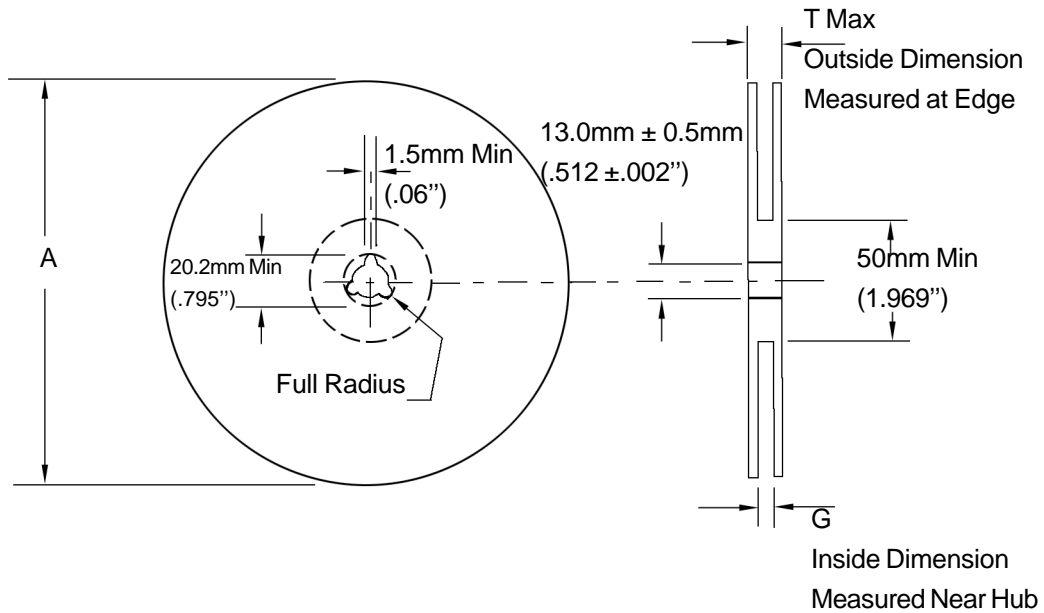
LSBTH10T1G

SC-74



DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.90	1.00	1.10	0.035	0.039	0.043
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.25	0.37	0.50	0.010	0.015	0.020
c	0.10	0.18	0.26	0.004	0.007	0.010
D	2.90	3.00	3.10	0.114	0.118	0.122
E	1.30	1.50	1.70	0.051	0.059	0.067
e	0.85	0.95	1.05	0.034	0.037	0.041
L	0.20	0.40	0.60	0.008	0.016	0.024
HE	2.50	2.75	3.00	0.099	0.108	0.118
θ	0°	-	10°	0°	-	10°

EMBOSSED TAPE AND REEL DATA FOR DISCRETES



Size	A Max	G	T Max
8 mm	178.0mm (7.0")	8.4mm+1.5mm, -0.0 (.33"+.039", -0.00)	10.9mm (.43")

Reel Dimensions

Metric Dimensions Govern — English are in parentheses for reference only

Storage Conditions

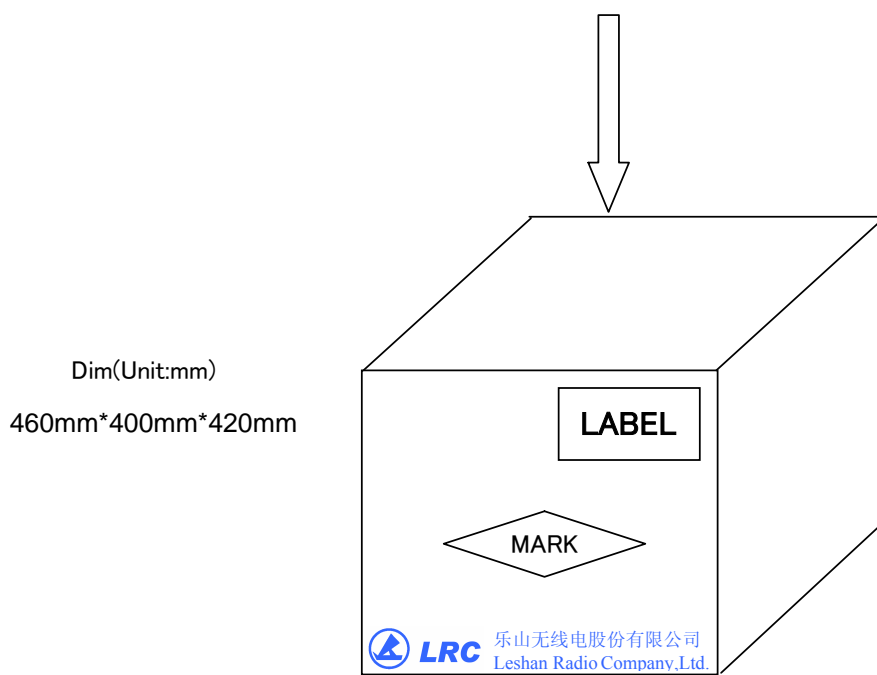
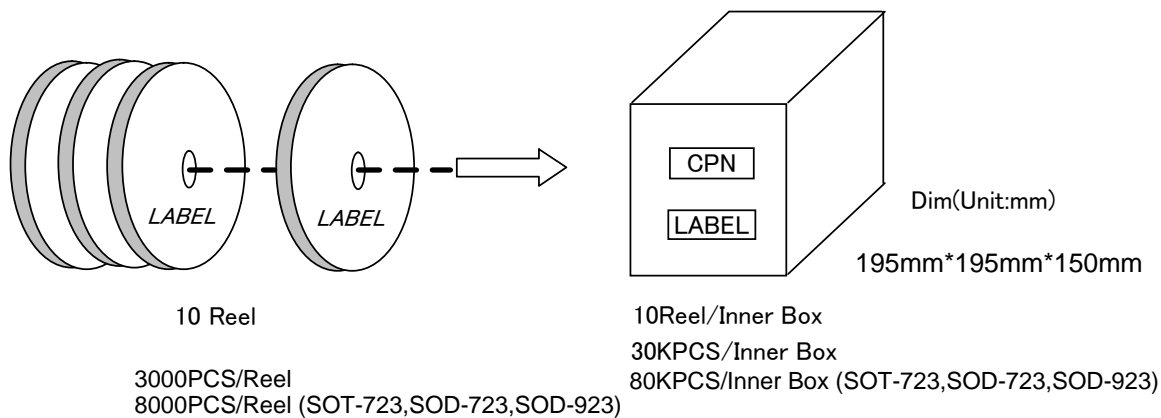
Temperature: 5 to 40 Deg.C (20 to 30 Deg. C is preferred)

Humidity: 30 to 80 RH (40 to 60 is preferred)

Recommended Period: One year after manufacturing

(This recommended period is for the soldering condition only. The characteristics and reliabilities of the products are not restricted to this limitation)

Shipment Specification



12 Inner Box/Carton

360KPCS/Carton
960KPCS/Carton (SOT-723,SOD-723,SOD-923)